

Phase-Cut Dimmable and Active PFC for LED lighting With High Voltage MOSFET Integrated

DESCRIPTION

The TS19830CS is a phase-cut (TRIAC) dimmable constant current control IC with active power factor correction for AC-DC LED lighting control. The TS19830CS is configurable as a non-isolated Buck-Boost converter which integrated 500V power MOSFET. It is compatible with many types of TRIAC dimmers including leading edge and trailing-edge. The IC achieves a high power factor and low total harmonic distortion (THD) and guarantees constant current accuracy to $<\pm 2.5\%$ using Discontinuous Conduction Mode (DCM) operation. The TS19830CS has built-in protection circuits such as over temperature protection by current degeneration, VCC overvoltage protection and system output open/short circuit protection.

FEATURES

- Phase cut dimmable
- Integrated 500V MOSFET
- Low THD $<10\%$
- Good dimmer compatibility for 120/230V_{AC} Lamps
- Constant Current Accuracy within $\pm 2.5\%$
- High Power Factor >0.9
- Low BOM Cost Design
- Discontinuous Conduction Mode Control (DCM)
- LED Open Protection
- LED Short protection
- Over Current Protection (OCP)
- Over Thermal Protection (OTP)
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC.
- Halogen-free according to IEC 61249-2-21

APPLICATION

- LED lighting
- Down lights, Tube lamps, PAR Lamps, Bulbs

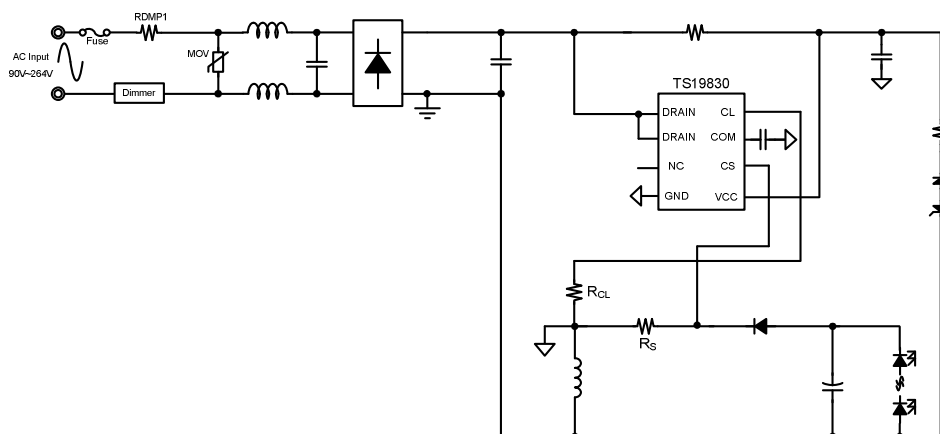


Pin Definition:

- | | |
|--------|----------|
| 1. VCC | 8. GND |
| 2. CS | 7. NC |
| 3. COM | 6. DRAIN |
| 4. CL | 5. DRAIN |

Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

TYPICAL APPLICATION CIRCUIT



ABSOLUTE MAXIMUM RATINGS (Note 1)			
PARAMETER	SYMBOL	LIMIT	UNIT
Power Supply Pin	V_{CC}	40	V
CS Voltage to GND	V_{CS}	-0.3 to 5.5	V
DRAIN Voltage to GND	V_{DRAIN}	-0.3 to 500	V
CS Voltage to GND	V_{CS}	-0.3 to 5.5	V
CL Voltage to GND	V_{CL}	-0.3 to 5.5	V
COM Voltage to GND	V_{COM}	-0.3 to 5.5	V
Junction Temperature Range	T_J	-40 to +150	°C
Storage Temperature Range	T_{STG}	-65 to +150	°C
Lead Temperature (Soldering 10s)	T_{LEAD}	260	°C
Power Dissipation @ $T_A=25\text{ }^\circ\text{C}$	P_D	0.6	W
ESD Rating (Human Body Mode) (Note2)	HBM	2	kV
ESD Rating (Machine Mode) (Note 2)	MM	200	V

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Thermal Resistance - Junction to Case	$R_{\theta JC}$	50	°C/W
Thermal Resistance - Junction to Ambient	$R_{\theta JA}$	208	°C/W

Note: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB in still air. Thermal Resistance is specified with the component mounted on a low effective thermal conductivity test board in free air at $T_A=25^\circ\text{C}$.

RECOMMENDED OPERATING CONDITIONS (Note 3)			
PARAMETER	SYMBOL	CONDITIONS	UNIT
Power Supply Pin	V_{CC}	33	V
CL Voltage to GND	V_{CL}	-0.3 to 0.3	V
DRAIN Voltage to GND	V_{DRAIN}	-0.3 to 500	V
CS Voltage to GND	V_{CS}	-0.3 to 5	V
COM Voltage to GND	V_{COM}	-0.3 to 5	V
Operating Junction Temperature Range	T_J	-40 to +125	°C
Operating Ambient Temperature Range	T_{OPA}	-40 to +85	°C

ELECTRICAL SPECIFICATIONS ($V_{CC} = 18V, T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage						
Start-up Current	$V_{CC(ST)}$	$V_{CC} = V_{UVLO(on)} - 1V$	--	45	--	μA
Operating Current	I_{OPA}	Operating @ 60kHz	--	2.1	2.6	mA
UVLO(off)	$V_{UVLO(off)}$		7	8	9	V
UVLO(on)	$V_{UVLO(on)}$		16	17.5	19	V
OVP Level on V_{CC} Pin	V_{OVP}		29	31	33	V
Voltage Feedback						
Feedback Reference Voltage	V_{FB}		0.196	0.2	0.204	V
Transconductance	g_m		--	58	--	μS
Output Sink Current	I_{O-SINK}		--	5.8	--	μA
Output Source Current	$I_{O-SOURCE}$		--	5.8	--	μA
Current Sensing						
Open Loop Voltage	V_{OLP}	CS Pin Open	--	5	--	V
Leading-Edge Blanking Time	t_{LEB}		--	400	--	ns
Delay to Output	t_{DELAY}		--	100	--	ns
Current Limit						
CL Limit Voltage	V_{OCP}		--	0.3	--	V
Switching Frequency						
Start Frequency	f_{STR}		--	4.5	--	kHz

ELECTRICAL SPECIFICATIONS ($V_{CC} = 18V, T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
MOSFET section						
Drain-Source Breakdown Voltage	BV_{DS}		500	--	--	V
Drain-Source On Resistance	$R_{DS(ON)}$		--	2.3	--	Ω
Thermal Section (Note 5,6)						
Thermal Shutdown			--	150	--	$^{\circ}C$
Thermal Shutdown Release			--	120	--	$^{\circ}C$

Note:

- Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Devices are ESD sensitive. Handling precaution recommended.
- Thermal Resistance is specified with the component mounted on a low effective thermal conductivity test board in free air at $T_A = 25^{\circ}C$.
- The device is not guaranteed to function outside its operating conditions.
- Guaranteed by design.
- Auto Recovery Type.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TS19830CS RLG	SOP-8	2,500pcs / 13"Reel

BLOCK DIAGRAM

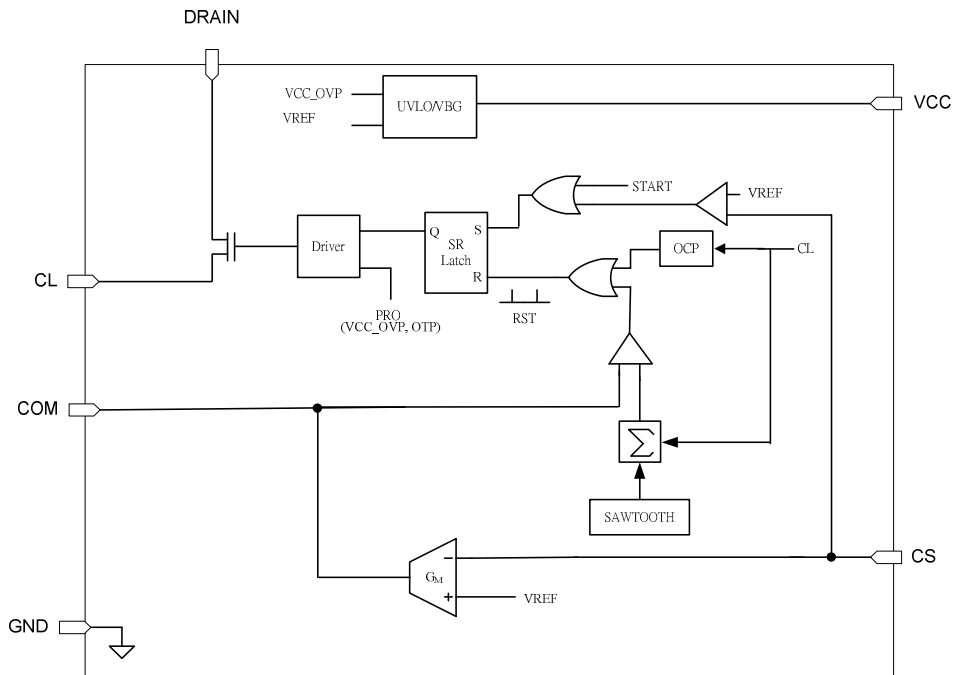


Fig. 1

PIN DESCRIPTION

PIN NO.	NAME	FUNCTION
1	V _{CC}	Power supply pin for all internal circuitry.
2	CS	Input current sense pin.
3	COM	Output pin of error amplifier.
4	CL	Current limit.
5.6	DRAIN	High Voltage MOSFET Drain
7	N/C	No connect
8	GND	Ground return for all internal circuitry.

APPLICATION INFORMATION

Start-up Current

The typical start-up current is around 45μA. Very low start-up current allows the PWM controller to increase the value of start-up resistor and then reduce the power dissipation.

UVLO(Under Voltage Lockout)

A hysteresis UVLO comparator is implemented in TS19830. The turn-on and turn-off thresholds level are fixed at 17.5V and 8V respectively. This hysteresis shown in Fig.2 ensures that the start-up capacitor will be adequate to supply the chip during start-up. For quick start-up of the LED driver, the start-up resistor should be matched with the start-up capacitor.

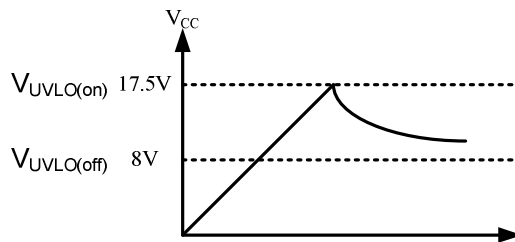


Fig. 2

LEB(Leading-Edge Blanking)

Each time the power MOSFET is switched on, a turn-on spike will inevitably occur at the sense resistor. To avoid fault trigger, a 400ns leading-edge blanking time is built in. Conventional RC filtering can therefore be omitted. During this blanking period, the current-limit comparator is disabled and cannot switch off the gate driver.

OCP(Over Current Protection)

The TS19830 has built-in cycle by cycle over current protection function on CL pin. As the CL pin voltage is larger than V_{OCP} (0.3V), the gate output will be turned off immediately to avoid the driver board to be burned out.

OVP (Over Voltage Protection) on V_{CC}

To prevent the LED driver from being damaged, the TS19830 has an implemented OVP function on V_{CC} . When the V_{CC} voltage is higher than the V_{OVP} (31V), the output gate driver circuit will be shut down immediately to stop the switching of power MOSFET. The V_{CC} pin OVP function is an auto recovery type protection. If the OVP condition happens, the pulses will be stopped until the V_{CC} pin voltage is down to the UVLO off level. The TS19830 is working in an auto-recovery mode as shown in Fig. 3.

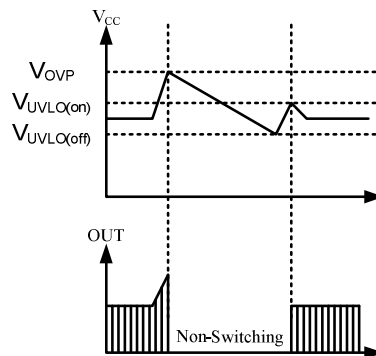


Fig. 3

CHARACTERISTICS CURVES

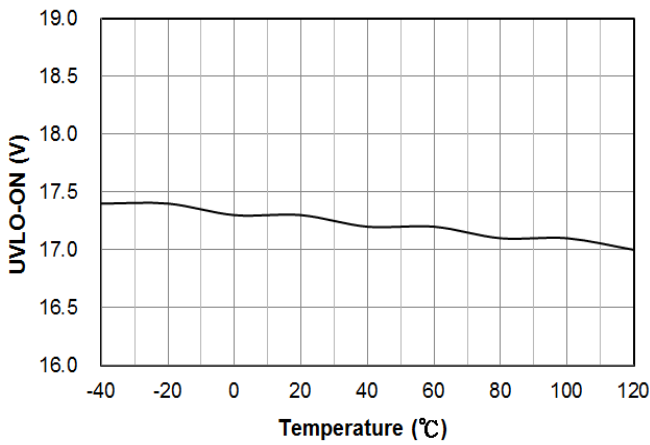


Figure 1 – UVLO-ON vs. Ambient Temperature

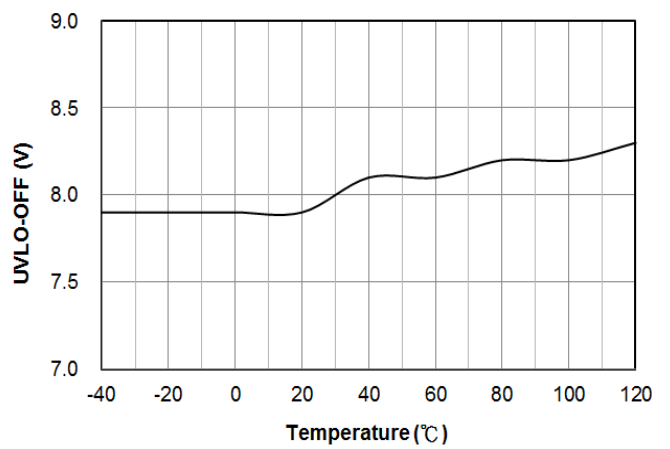


Figure 2 – UVLO-OFF vs. Ambient Temperature

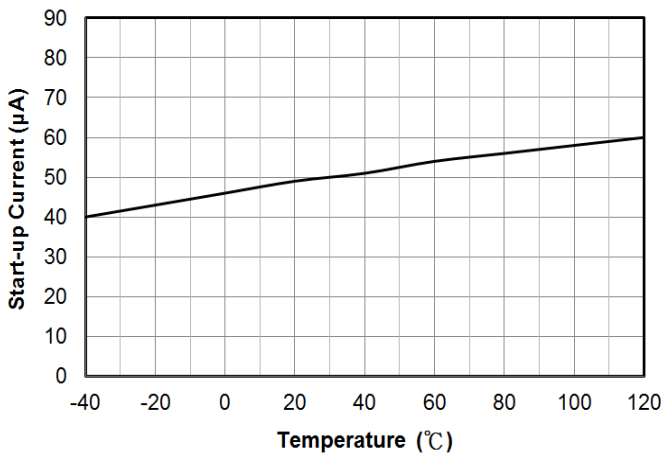


Figure 3 – Start-up Current vs. Ambient Temperature

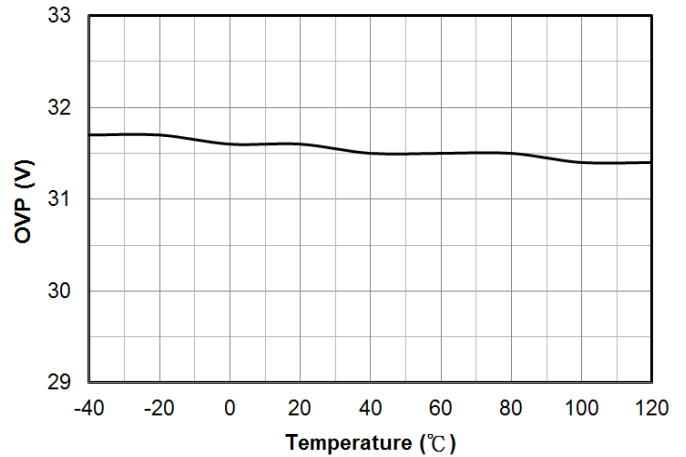


Figure 4 – OVP vs. Ambient Temperature

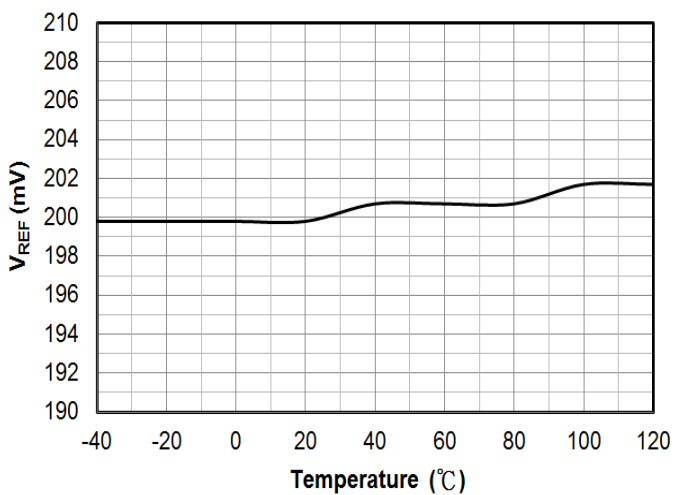


Figure 5 – V_{REF} vs. Ambient Temperature

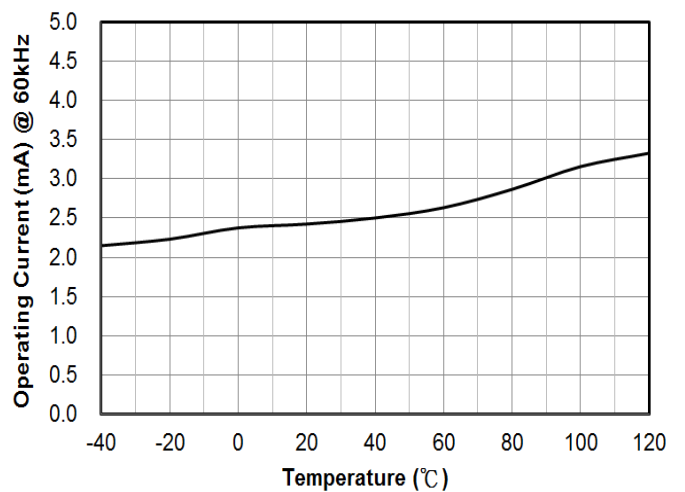
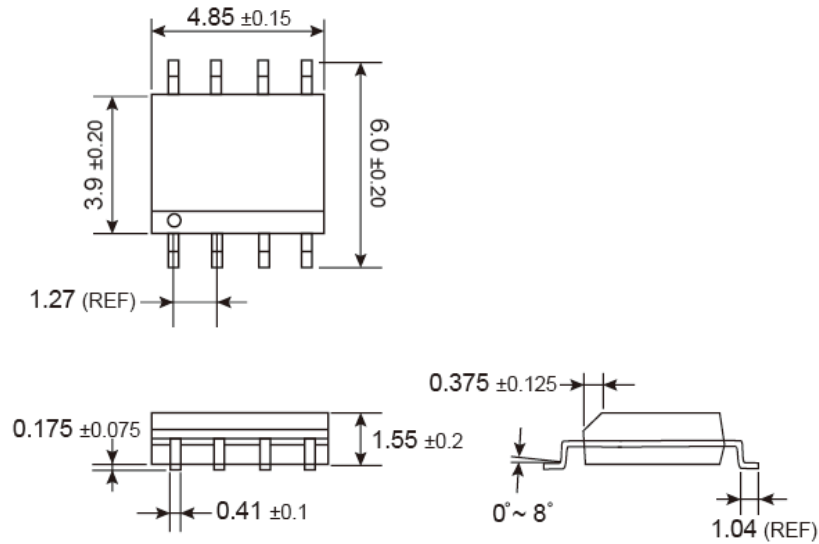


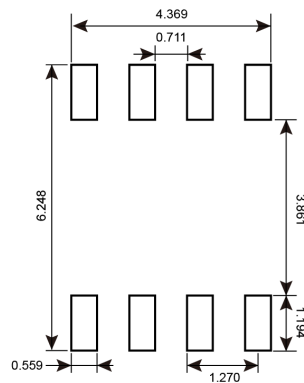
Figure 6 – Operating Current vs. Ambient Temperature

PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

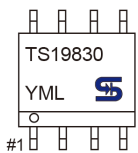
SOP-8



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



- Y** = Year Code
- M** = Month Code for Halogen Free Product
 - O** =Jan **P** =Feb **Q** =Mar **R** =Apr
 - S** =May **T** =Jun **U** =Jul **V** =Aug
 - W** =Sep **X** =Oct **Y** =Nov **Z** =Dec
- L** = Lot Code (1~9, A~Z)

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